

Quad Analog Switch/ Multiplexer/Demultiplexer with Separate Analog and Digital Power Supplies

High-Performance Silicon-Gate CMOS

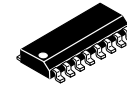
MC74HC4316A

The MC74HC4316A utilizes silicon-gate CMOS technology to achieve fast propagation delays, low ON resistances, and low OFF-channel leakage current. This bilateral switch/multiplexer/demultiplexer controls analog and digital voltages that may vary across the full analog power-supply range (from V_{CC} to V_{EE}).

The HC4316A is similar in function to the metal-gate CMOS MC14016 and MC14066, and to the High-Speed CMOS HC4066A. Each device has four independent switches. The device control and Enable inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs. The device has been designed so that the ON resistances (R_{ON}) are much more linear over input voltage than R_{ON} of metal-gate CMOS analog switches. Logic-level translators are provided so that the On/Off Control and Enable logic-level voltages need only be V_{CC} and GND, while the switch is passing signals ranging between V_{CC} and V_{EE} . When the Enable pin (active-low) is high, all four analog switches are turned off.

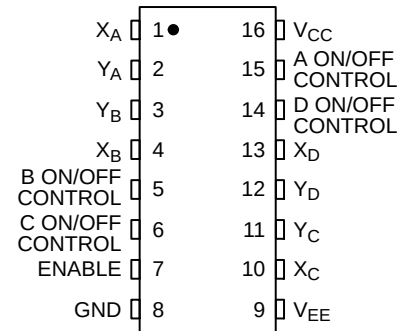
Features

- Logic-Level Translator for On/Off Control and Enable Inputs
- Fast Switching and Propagation Speeds
- High ON/OFF Output Voltage Ratio
- Diode Protection on All Inputs/Outputs
- Analog Power-Supply Voltage Range ($V_{CC} - V_{EE}$) = 2.0 to 12.0 V
- Digital (Control) Power-Supply Voltage Range ($V_{CC} - GND$) = 2.0 V to 6.0 V, Independent of V_{EE}
- Improved Linearity of ON Resistance
- Chip Complexity: 66 FETs or 16.5 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable*
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

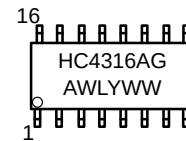


SOIC-16
D SUFFIX
CASE 751B

PIN ASSIGNMENT



MARKING DIAGRAM



A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74HC4316ADR2G	SOIC-16 (Pb-Free)	2500/ Tape&Reel

DISCONTINUED (Note 1)

NLV74HC4316ADR2G*	SOIC-16 (Pb-Free)	2500/ Tape&Reel
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[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

1. **DISCONTINUED:** This device is not recommended for new design. Please contact your onsemi representative for information. The most current information on this device may be available on www.onsemi.com.

MC74HC4316A

FUNCTION TABLE

Inputs		State of Analog Switch
Enable	On/Off Control	
L	H	On
L	L	Off
H	X	Off

X = Don't Care.

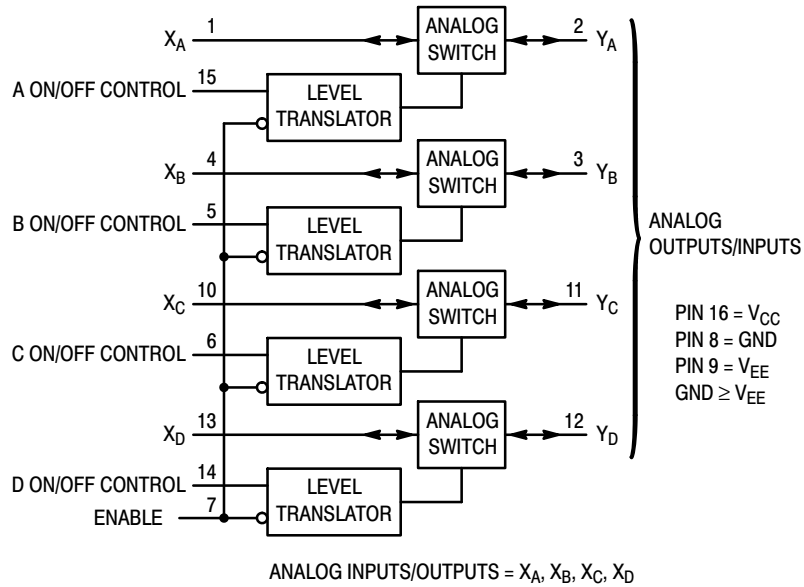


Figure 1. Logic Diagram

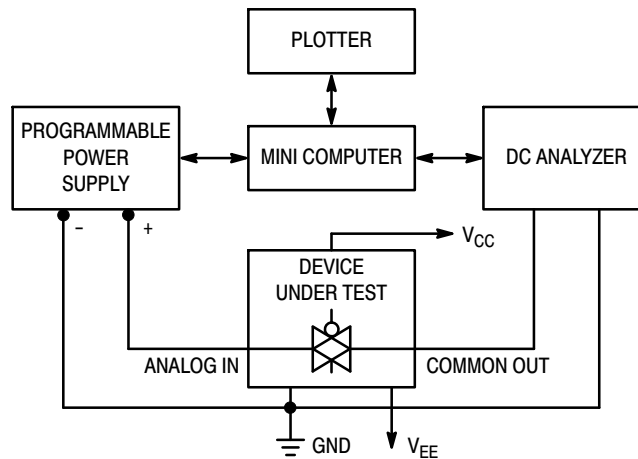


Figure 2. On Resistance Test Set-Up

MC74HC4316A

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Positive DC Supply Voltage (Ref. to GND) (Ref. to V_{EE})	−0.5 to +7.0 −0.5 to +14.0	V
V_{EE}	Negative DC Supply Voltage (Ref. to GND)	−7.0 to +0.5	V
V_{IS}	Analog Input Voltage	$V_{EE} - 0.5$ to $V_{CC} + 0.5$	V
V_{in}	DC Input Voltage (Ref. to GND)	−0.5 to $V_{CC} + 0.5$	V
I	DC Current Into or Out of Any Pin	±25	mA
P_D	Power Dissipation in Still Air SOIC Package*	500	mW
T_{stg}	Storage Temperature	− 65 to + 150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds)	260	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $GND \leq (V_{in} \text{ or } V_{out}) \leq V_{CC}$. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open. I/O pins must be connected to a properly terminated line or bus.

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

*Derating – SOIC Package: −7 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	Positive DC Supply Voltage (Ref. to GND)	2.0	6.0	V
V _{EE}	Negative DC Supply Voltage (Ref. to GND)	−6.0	GND	V
V _{IS}	Analog Input Voltage	V _{EE}	V _{CC}	V
V _{in}	Digital Input Voltage (Ref. to GND)	GND	V _{CC}	V
V _{IO} *	Static or Dynamic Voltage Across Switch	−	1.2	V
T _A	Operating Temperature, All Package Types	−55	+125	°C
t _r , t _f	Input Rise and Fall Time (Control or Enable Inputs) (Figure 10)	V _{CC} = 2.0 V 0 V _{CC} = 3.0 V 0 V _{CC} = 4.5 V 0 V _{CC} = 6.0 V	1000 600 500 400	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

*For voltage drops across the switch greater than 1.2 V (switch on), excessive V_{CC} current may be drawn; i.e., the current out of the switch may contain both V_{CC} and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded.

DC ELECTRICAL CHARACTERISTICS Digital Section (Voltages Referenced to GND) $V_{EE} = GND$ Except Where Noted

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit			Unit
				−55 to 25°C	≤ 85°C	≤ 125°C	
V_{IH}	Minimum High-Level Voltage, Control or Enable Inputs	$R_{on} = \text{Per Spec}$	2.0 3.0 4.5 6.0	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	V
V_{IL}	Maximum Low-Level Voltage, Control or Enable Inputs	$R_{on} = \text{Per Spec}$	2.0 3.0 4.5 6.0	0.5 0.9 1.35 1.8	0.5 0.9 1.35 1.8	0.5 0.9 1.35 1.8	V
I_{in}	Maximum Input Leakage Current, Control or Enable Inputs	$V_{in} = V_{CC}$ or GND $V_{EE} = -6.0 \text{ V}$	6.0	±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current (per Package)	$V_{in} = V_{CC}$ or GND $V_{IO} = 0 \text{ V}$ $V_{EE} = GND$ $V_{EE} = -6.0$	6.0 6.0	2 4	20 40	40 160	μA

MC74HC4316A

DC ELECTRICAL CHARACTERISTICS Analog Section (Voltages Referenced to V_{EE})

Symbol	Parameter	Test Conditions	V_{CC} V	V_{EE} V	Guaranteed Limit			Unit
					-55 to 25°C	≤ 85°C	≤ 125°C	
R_{on}	Maximum "ON" Resistance	$V_{in} = V_{IH}$ $V_{IS} = V_{CC}$ to V_{EE} $I_S \leq 2.0$ mA (Figure 2)	2.0*	0.0	–	–	–	Ω
			4.5	0.0	160	200	240	
			4.5	-4.5	90	110	130	
			6.0	-6.0	90	110	130	
		$V_{in} = V_{IH}$ $V_{IS} = V_{CC}$ or V_{EE} (Endpoints) $I_S \leq 2.0$ mA (Figure 2)	2.0	0.0	–	–	–	
			4.5	0.0	90	115	140	
ΔR_{on}	Maximum Difference in "ON" Resistance Between Any Two Channels in the Same Package	$V_{in} = V_{IH}$ $V_{IS} = 1/2 (V_{CC} - V_{EE})$ $I_S \leq 2.0$ mA	2.0	0.0	–	–	–	Ω
			4.5	0.0	20	25	30	
			4.5	-4.5	15	20	25	
			6.0	-6.0	15	20	25	
I_{off}	Maximum Off-Channel Leakage Current, Any One Channel	$V_{in} = V_{IL}$ $V_{IO} = V_{CC}$ or V_{EE} Switch Off (Figure 3)	6.0	-6.0	0.1	0.5	1.0	μA
I_{on}	Maximum On-Channel Leakage Current, Any One Channel	$V_{in} = V_{IH}$ $V_{IS} = V_{CC}$ or V_{EE} (Figure 4)	6.0	-6.0	0.1	0.5	1.0	μA

*At supply voltage ($V_{CC} - V_{EE}$) approaching 2.0 V the analog switch-on resistance becomes extremely non-linear. Therefore, for low-voltage operation, it is recommended that these devices only be used to control digital signals.

AC ELECTRICAL CHARACTERISTICS ($C_L = 50$ pF, Control or Enable $t_r = t_f = 6$ ns, $V_{EE} = GND$)

Symbol	Parameter	V_{CC} V	Guaranteed Limit			Unit
			-55 to 25°C	≤ 85°C	≤ 125°C	
t_{PLH} , t_{PHL}	Maximum Propagation Delay, Analog Input to Analog Output (Figures 8 and 9)	2.0 4.5 6.0	40 6 5	50 8 7	60 9 8	ns
t_{PLZ} , t_{PHZ}	Maximum Propagation Delay, Control or Enable to Analog Output (Figures 10 and 11)	2.0 4.5 6.0	130 40 30	160 50 40	200 60 50	ns
t_{PZL} , t_{PZH}	Maximum Propagation Delay, Control or Enable to Analog Output (Figures 10 and 11)	2.0 4.5 6.0	140 40 30	175 50 40	250 60 50	ns
C	Maximum Capacitance ON/OFF Control and Enable Inputs Control Input = GND Analog I/O Feedthrough	–	10	10	10	pF
		–	35	35	35	
		–	1.0	1.0	1.0	

C _{PD}	Power Dissipation Capacitance (Per Switch) (Figure 13)*	Typical @ 25°C, V _{CC} = 5.0 V	pF
		15	

*Used to determine the no-load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

MC74HC4316A

ADDITIONAL APPLICATION CHARACTERISTICS (GND = 0 V)

Symbol	Parameter	Test Conditions	V _{CC} V	V _{EE} V	Limit* 25°C	Unit
BW	Maximum On-Channel Bandwidth or Minimum Frequency Response (Figure 5)	f _{in} = 1 MHz Sine Wave Adjust f _{in} Voltage to Obtain 0 dBm at V _{OS} Increase f _{in} Frequency Until dB Meter Reads -3 dB R _L = 50 Ω, C _L = 10 pF	2.25 4.50 6.00	-2.25 -4.50 -6.00	150 160 160	MHz
-	Off-Channel Feedthrough Isolation (Figure 6)	f _{in} ≡ Sine Wave Adjust f _{in} Voltage to Obtain 0 dBm at V _{IS} f _{in} = 10 kHz, R _L = 600 Ω, C _L = 50 pF f _{in} = 1.0 MHz, R _L = 50 Ω, C _L = 10 pF	2.25 4.50 6.00 2.25 4.50 6.00	-2.25 -4.50 -6.00 -2.25 -4.50 -6.00	-50 -50 -50 -40 -40 -40	dB
-	Feedthrough Noise, Control to Switch (Figure 7)	V _{in} ≤ 1 MHz Square Wave (t _r = t _f = 6 ns) Adjust R _L at Setup so that I _S = 0 A R _L = 600 Ω, C _L = 50 pF R _L = 10 kΩ, C _L = 10 pF	2.25 4.50 6.00 2.25 4.50 6.00	-2.25 -4.50 -6.00 -2.25 -4.50 -6.00	30 65 100 60 130 200	mV _{PP}
-	Crosstalk Between Any Two Switches (Figure 12)	f _{in} ≡ Sine Wave Adjust f _{in} Voltage to Obtain 0 dBm at V _{IS} f _{in} = 10 kHz, R _L = 600 Ω, C _L = 50 pF f _{in} = 1.0 MHz, R _L = 50 Ω, C _L = 10 pF	2.25 4.50 6.00 2.25 4.50 6.00	-2.25 -4.50 -6.00 -2.25 -4.50 -6.00	-70 -70 -70 -80 -80 -80	dB
THD	Total Harmonic Distortion (Figure 14)	f _{in} = 1 kHz, R _L = 10 kΩ, C _L = 50 pF THD = THD _{Measured} - THD _{Source} V _{IS} = 4.0 V _{PP} sine wave V _{IS} = 8.0 V _{PP} sine wave V _{IS} = 11.0 V _{PP} sine wave	2.25 4.50 6.00	-2.25 -4.50 -6.00	0.10 0.06 0.04	%

*Limits not tested. Determined by design and verified by qualification.

MC74HC4316A

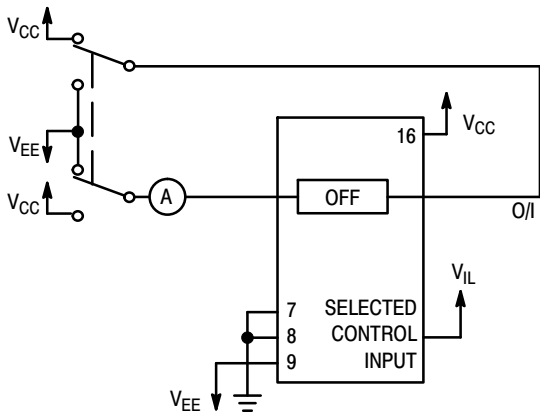


Figure 3. Maximum Off Channel Leakage Current, Any One Channel, Test Set-Up

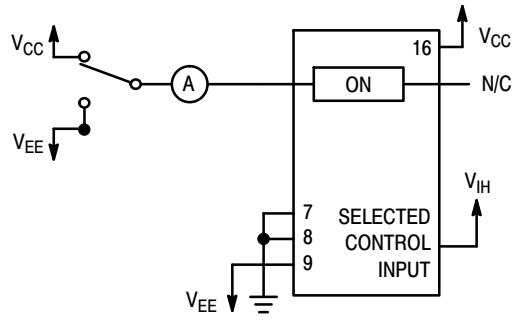
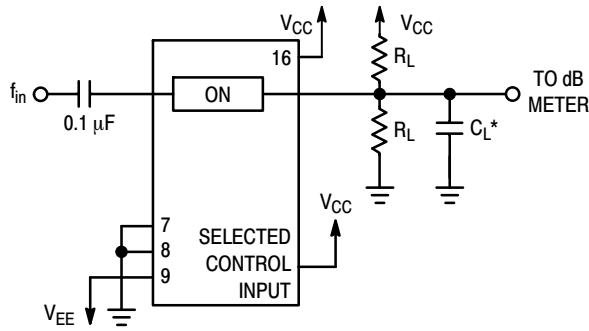
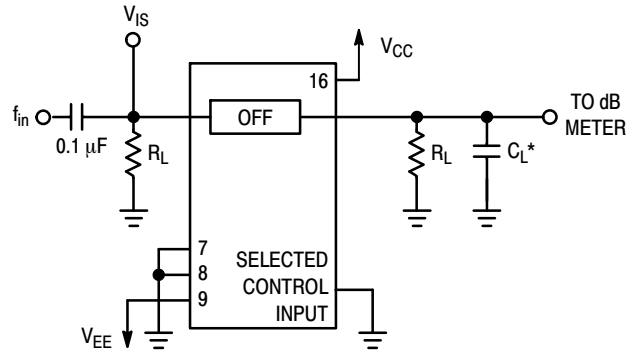


Figure 4. Maximum On Channel Leakage Current, Test Set-Up



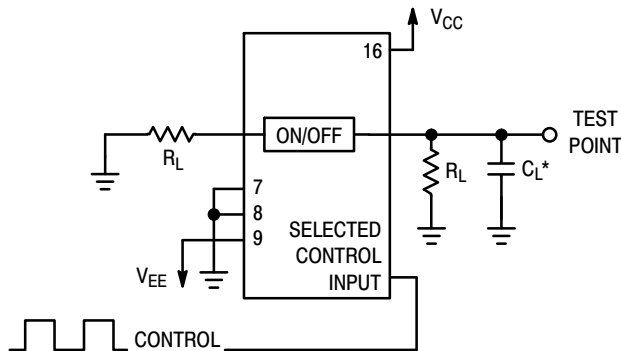
*Includes all probe and jig capacitance.

Figure 5. Maximum On-Channel Bandwidth Test Set-Up



*Includes all probe and jig capacitance.

Figure 6. Off-Channel Feedthrough Isolation, Test Set-Up



*Includes all probe and jig capacitance.

Figure 7. Feedthrough Noise, Control to Analog Out, Test Set-Up

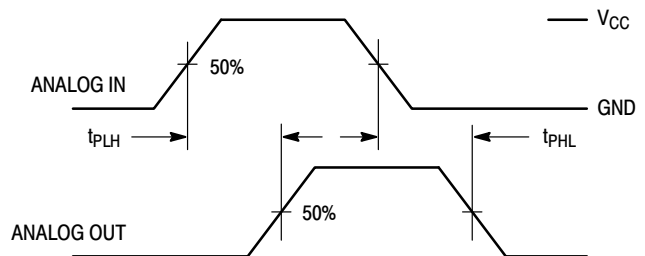
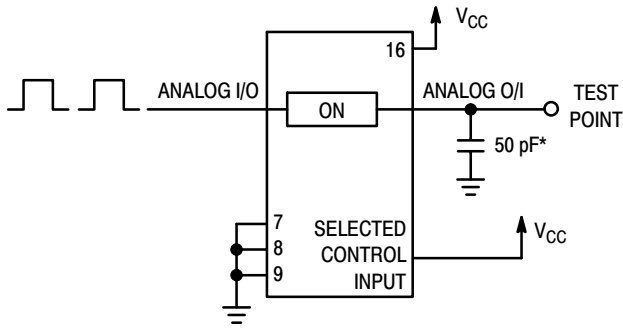


Figure 8. Propagation Delays, Analog In to Analog Out

MC74HC4316A



*Includes all probe and jig capacitance.

Figure 9. Propagation Delay Test Set-Up

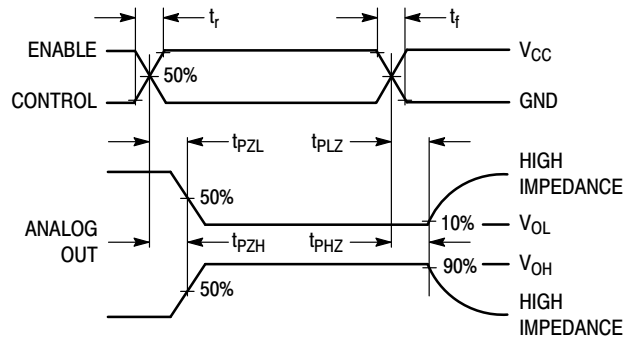
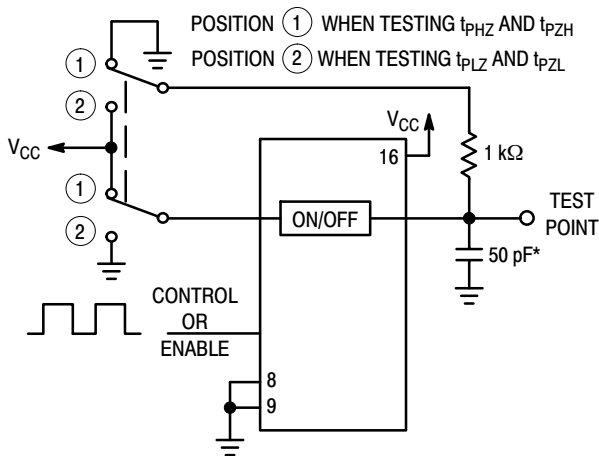
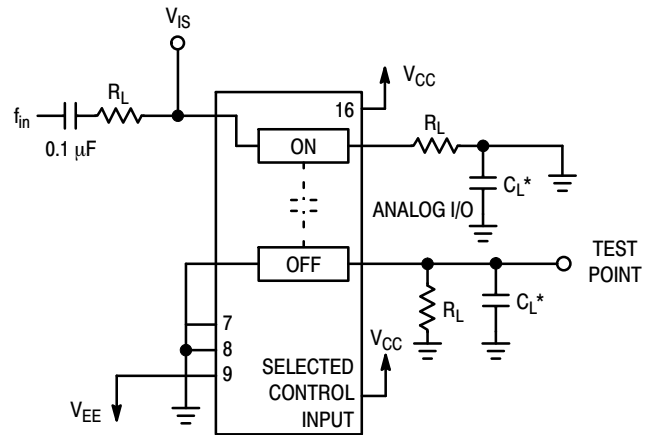


Figure 10. Propagation Delay, ON/OFF Control to Analog Out



*Includes all probe and jig capacitance.

Figure 11. Propagation Delay Test Set-Up



*Includes all probe and jig capacitance.

Figure 12. Crosstalk Between Any Two Switches, Test Set-Up (Adjacent Channels Used)

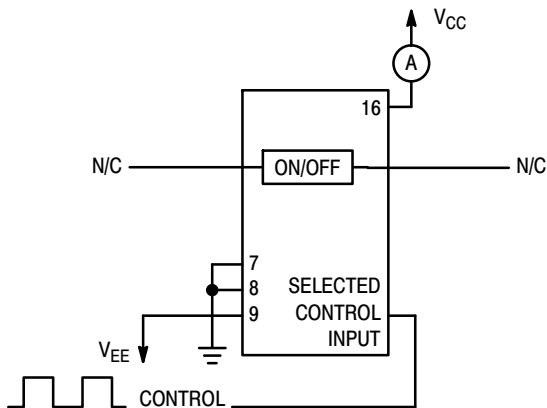
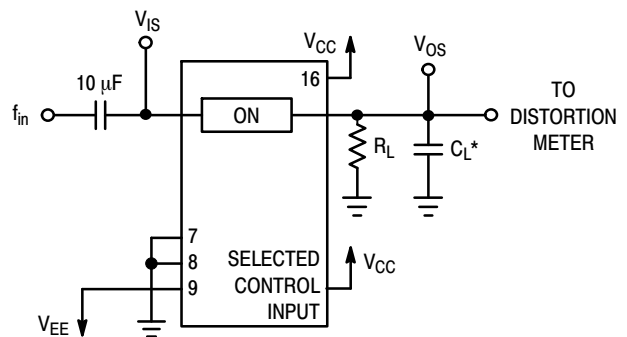


Figure 13. Power Dissipation Capacitance Test Set-Up



*Includes all probe and jig capacitance.

Figure 14. Total Harmonic Distortion, Test Set-Up

APPLICATIONS INFORMATION

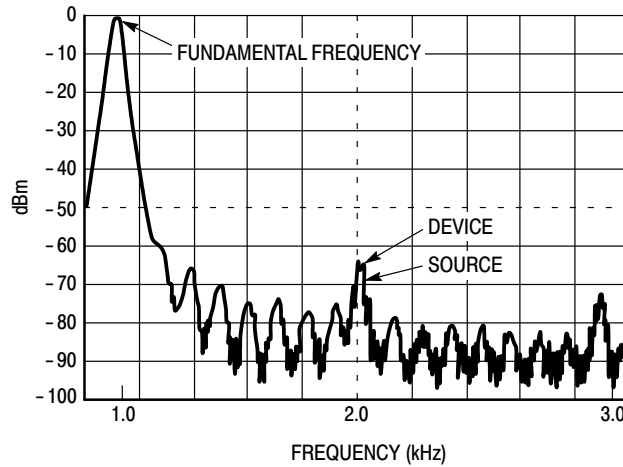


Figure 15. Plot, Harmonic Distortion

The Enable and Control pins should be at V_{CC} or GND logic levels, V_{CC} being recognized as logic high and GND being recognized as a logic low. Unused analog inputs/outputs may be left floating (not connected). However, it is advisable to tie unused analog inputs and outputs to V_{CC} or V_{EE} through a low value resistor. This minimizes crosstalk and feedthrough noise that may be picked up by the unused I/O pins.

The maximum analog voltage swings are determined by the supply voltages V_{CC} and V_{EE} . The positive peak analog voltage should not exceed V_{CC} . Similarly, the negative peak analog voltage should not go below V_{EE} . In the example below, the difference between V_{CC} and V_{EE} is 12 V.

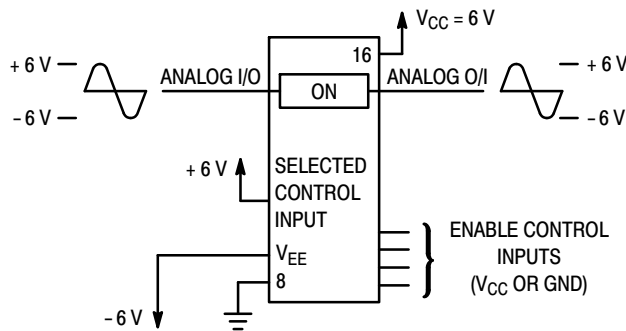


Figure 16.

Therefore, using the configuration in Figure 16, a maximum analog signal of twelve volts peak-to-peak can be controlled.

When voltage transients above V_{CC} and/or below V_{EE} are anticipated on the analog channels, external diodes (D_x) are recommended as shown in Figure 17. These diodes should be small signal, fast turn-on types able to absorb the maximum anticipated current surges during clipping. An alternate method would be to replace the D_x diodes with MOSORBs (MOSORB[®] is an acronym for high current surge protectors). MOSORBs are fast turn-on devices ideally suited for precise dc protection with no inherent wear out mechanism.

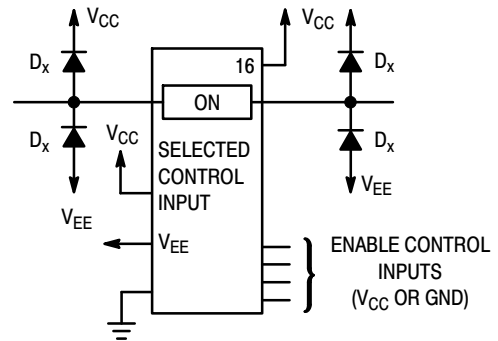


Figure 17. Transient Suppressor Application

MC74HC4316A

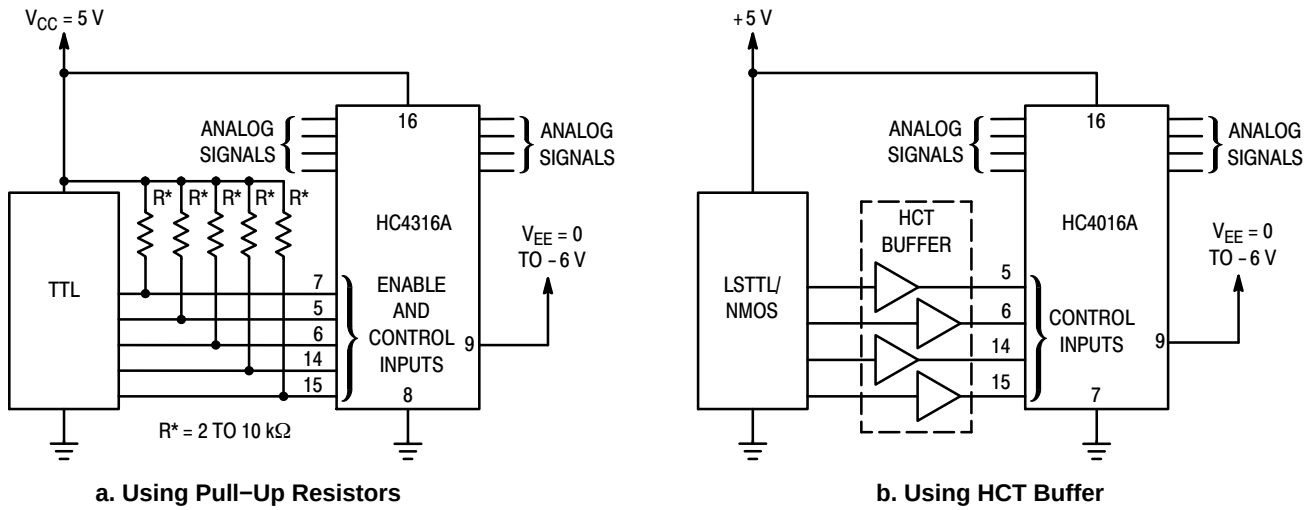


Figure 18. LSTTL/NMOS to HCMOS Interface

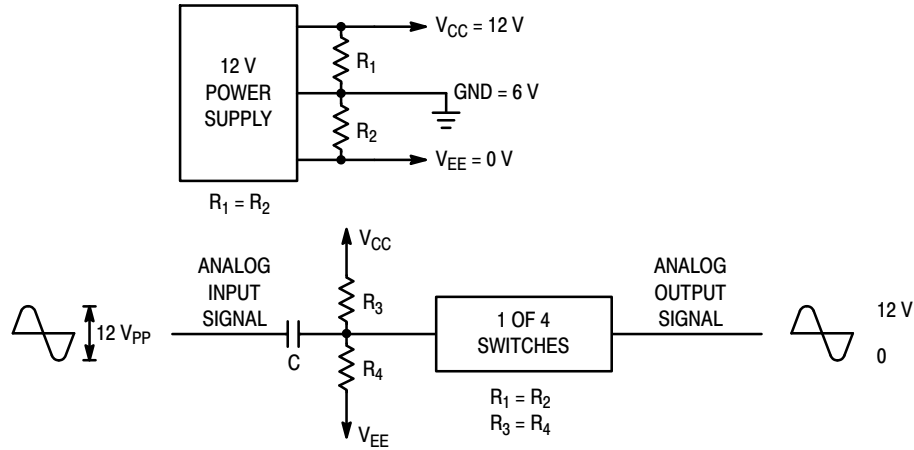


Figure 19. Switching a 0-to-12 V Signal Using a Single Power Supply ($GND \neq 0V$)

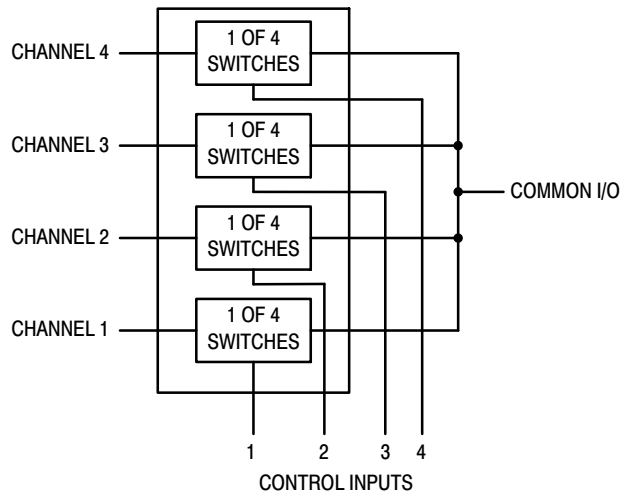


Figure 20. 4-Input Multiplexer

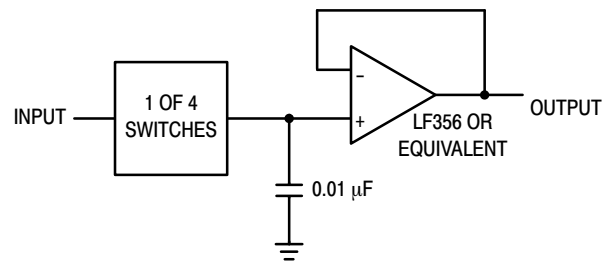
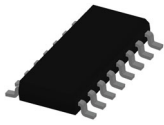


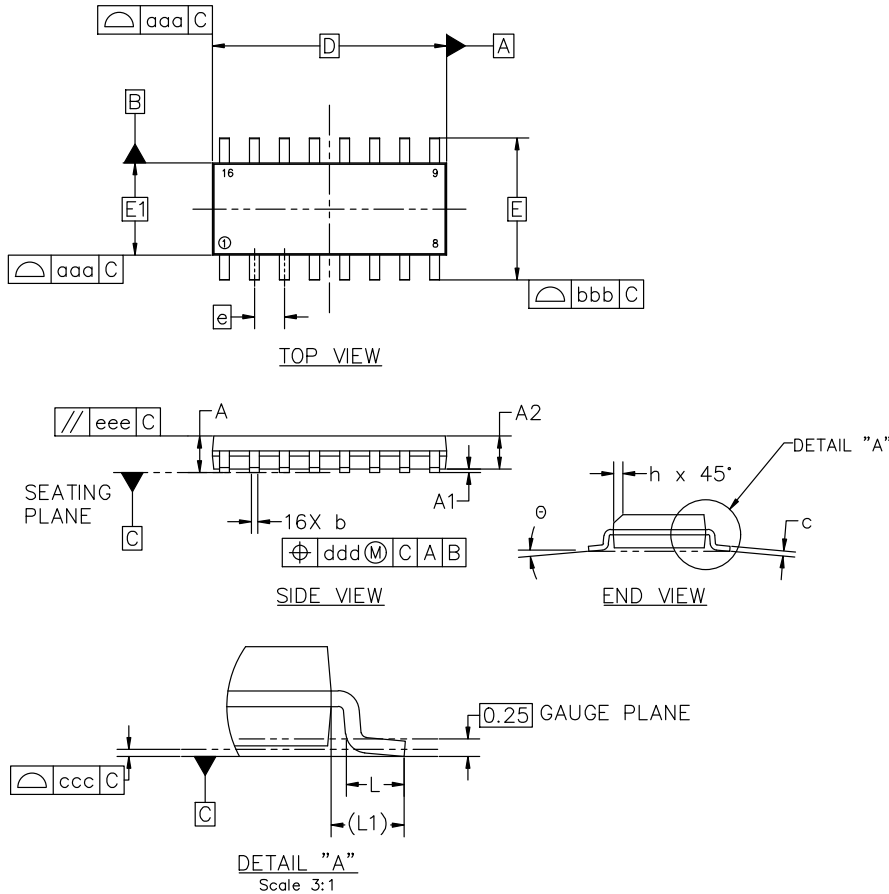
Figure 21. Sample/Hold Amplifier


SOIC-16 9.90x3.90x1.37 1.27P
CASE 751B
ISSUE M

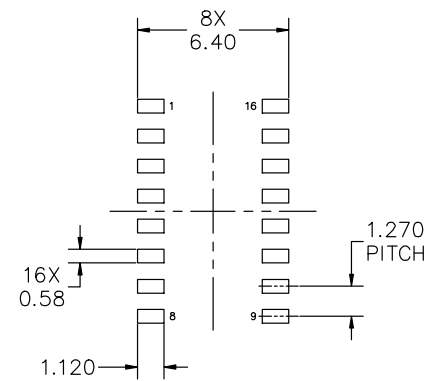
DATE 18 OCT 2024

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15mm PER SIDE.
5. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127mm TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.



MILLIMETERS			
DIM	MIN	NOM	MAX
A	1.35	1.55	1.75
A1	0.10	0.18	0.25
A2	1.25	1.37	1.50
b	0.35	0.42	0.49
c	0.19	0.22	0.25
D	9.90 BSC		
E	6.00 BSC		
E1	3.90 BSC		
e	1.27 BSC		
h	0.25	---	0.50
L	0.40	0.83	1.25
L1	1.05 REF		
θ	0°	---	7°
TOLERANCE OF FORM AND POSITION			
aaa	0.10		
bbb	0.20		
ccc	0.10		
ddd	0.25		
eee	0.10		



*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE onsemi SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERM/D

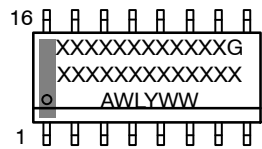
DOCUMENT NUMBER:	98ASB42566B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
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SOIC-16 9.90x3.90x1.37 1.27P
CASE 751B
ISSUE M

DATE 18 OCT 2024

GENERIC
MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: PIN 1. COLLECTOR 2. BASE 3. EMITTER 4. NO CONNECTION 5. EMITTER 6. BASE 7. COLLECTOR 8. COLLECTOR 9. BASE 10. EMITTER 11. NO CONNECTION 12. EMITTER 13. BASE 14. COLLECTOR 15. EMITTER 16. COLLECTOR	STYLE 2: PIN 1. CATHODE 2. ANODE 3. NO CONNECTION 4. CATHODE 5. CATHODE 6. NO CONNECTION 7. ANODE 8. CATHODE 9. CATHODE 10. ANODE 11. NO CONNECTION 12. CATHODE 13. CATHODE 14. NO CONNECTION 15. ANODE 16. CATHODE	STYLE 3: PIN 1. COLLECTOR, DYE #1 2. BASE, #1 3. EMITTER, #1 4. COLLECTOR, #1 5. COLLECTOR, #2 6. BASE, #2 7. EMITTER, #2 8. COLLECTOR, #2 9. COLLECTOR, #3 10. BASE, #3 11. EMITTER, #3 12. COLLECTOR, #3 13. COLLECTOR, #4 14. BASE, #4 15. EMITTER, #4 16. COLLECTOR, #4	STYLE 4: PIN 1. COLLECTOR, DYE #1 2. COLLECTOR, #1 3. COLLECTOR, #2 4. COLLECTOR, #2 5. COLLECTOR, #3 6. COLLECTOR, #3 7. COLLECTOR, #4 8. COLLECTOR, #4 9. BASE, #4 10. EMITTER, #4 11. BASE, #3 12. EMITTER, #3 13. BASE, #2 14. EMITTER, #2 15. BASE, #1 16. EMITTER, #1
STYLE 5: PIN 1. DRAIN, DYE #1 2. DRAIN, #1 3. DRAIN, #2 4. DRAIN, #2 5. DRAIN, #3 6. DRAIN, #3 7. DRAIN, #4 8. DRAIN, #4 9. GATE, #4 10. SOURCE, #4 11. GATE, #3 12. SOURCE, #3 13. GATE, #2 14. SOURCE, #2 15. GATE, #1 16. SOURCE, #1	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. CATHODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE 15. ANODE 16. ANODE	STYLE 7: PIN 1. SOURCE N-CH 2. COMMON DRAIN (OUTPUT) 3. COMMON DRAIN (OUTPUT) 4. GATE P-CH 5. COMMON DRAIN (OUTPUT) 6. COMMON DRAIN (OUTPUT) 7. COMMON DRAIN (OUTPUT) 8. SOURCE P-CH 9. SOURCE P-CH 10. COMMON DRAIN (OUTPUT) 11. COMMON DRAIN (OUTPUT) 12. COMMON DRAIN (OUTPUT) 13. GATE N-CH 14. COMMON DRAIN (OUTPUT) 15. COMMON DRAIN (OUTPUT) 16. SOURCE N-CH	

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